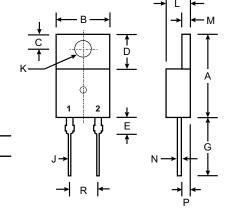


# MBR830 - MBR860

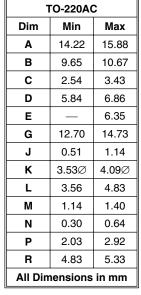
#### **8.0A SCHOTTKY BARRIER RECTIFIER**

#### **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Plastic Material: UL Flammability Classification Rating 94V-0



Pin 2 **0**-



### **Mechanical Data**

• Case: Molded Plastic

• Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208

Polarity: See Diagram

Weight: 2.24 grams (approx.)

Mounting Position: Any

Marking: Type Number

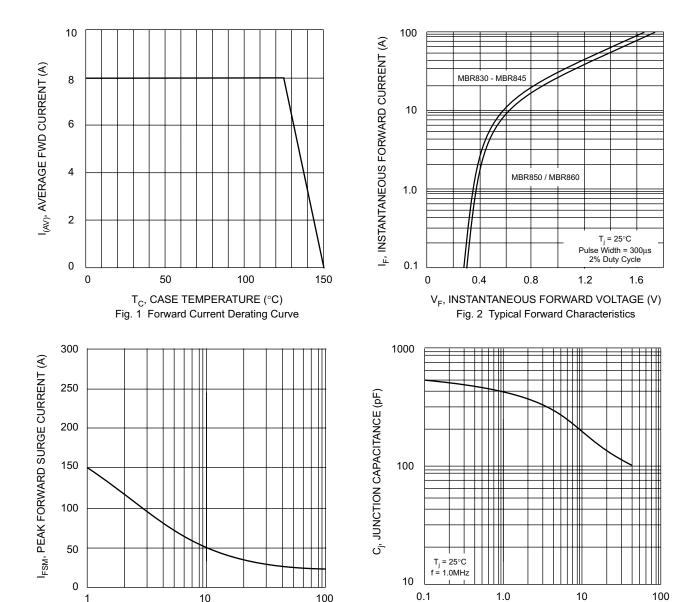
## Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol   | MBR<br>830           | MBR<br>835 | MBR<br>840 | MBR<br>845 | MBR<br>850 | MBR<br>860           | Unit |
|---|--|----------------------|------------|------------|------------|------------|----------------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 30                   | 35         | 40         | 45         | 50         | 60                   | V    |
| RMS Reverse Voltage   | V <sub>R(RMS)</sub>                                    | 21                   | 24.5       | 28         | 31.5       | 35         | 42                   | ٧    |
| Average Rectified Output Current (Note 1) @ T <sub>C</sub> = 125°   | c lo   | 8.0                  |            |            |            |            |                      | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms single half sine-wave superimposed on rated load<br>(JEDEC Method) | IFSM   | 150                  |            |            |            |            | A                    |      |
| Repetitive Peak Reverse Surge Current @ $t \le 2.0$   | μs I <sub>RRM</sub>                                    | 1.0                  |            |            |            |            | Α                    |      |
| Forward Voltage Drop  | °C V <sub>FM</sub>                                     | 0.57<br>0.70<br>0.84 |            |            |            | 0.         | 0.70<br>0.80<br>0.95 |      |
| $ \begin{array}{cccccccccccccccccccccccccccccccccccc$   |  | 0.1<br>15            |            |            |            |            | mA                   |      |
| Typical Junction Capacitance (Note 2)   | Cj   | 250                  |            |            |            | pF         |                      |      |
| Typical Thermal Resistance Junction to Case (Note 1)  | R <sub>0</sub> JC                                      | 3.0                  |            |            |            |            | K/W                  |      |
| Voltage Rate of Change (Rated V <sub>R</sub> )  | dV/dt  | 1000                 |            |            |            |            | V/µs                 |      |
| Operating and Storage Temperature Range   | T <sub>j</sub> , T <sub>STG</sub>                      | -65 to +150          |            |            |            |            | °C                   |      |

Notes: 1. Thermal resistance junction to case mounted on heatsink.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.



100

V<sub>R</sub>, REVERSE VOLTAGE (V)

Fig. 4 Typical Junction Capacitance

1

10

NUMBER OF CYCLES AT 60Hz

Fig. 3 Max Non-Repetitive Surge Current